NSN 5961-01-096-8159

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-096-8159 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.335 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 forward gate to source voltage and 60.0 drain to source voltage and 60.0 drain to gate voltage **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage source current horsepower metric and 2.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 6.25 watts small-signal input power, common-collector preset **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6675 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No